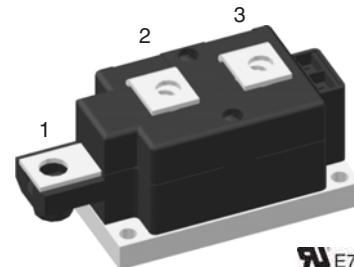
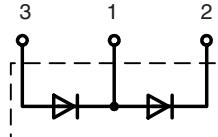


High Power Diode Modules

I_{FRMS} = 2x520 A
I_{FAVM} = 2x310 A
V_{RRM} = 1200-2200 V

V _{RSM} V	V _{RRM} V	Type
1300	1200	MDD 312-12N1
1500	1400	MDD 312-14N1
1700	1600	MDD 312-16N1
1900	1800	MDD 312-18N1
2100	2000	MDD 312-20N1
2300	2200	MDD 312-22N1



E72873

Symbol	Conditions	Maximum Ratings		
I _{FRMS}	T _{VJ} = T _{VJM}	520	A	
I _{FAVM}	T _C = 100°C; 180° sine	310	A	
I _{FSM}	T _{VJ} = 45°C; V _R = 0	t = 10 ms (50 Hz) t = 8.3 ms (60 Hz)	10500 11200	A
	T _{VJ} = T _{VJM} V _R = 0	t = 10 ms (50 Hz) t = 8.3 ms (60 Hz)	9200 9800	A
$\int i^2 dt$	T _{VJ} = 45°C V _R = 0	t = 10 ms (50 Hz) t = 8.3 ms (60 Hz)	551000 527000	A ² s
	T _{VJ} = T _{VJM} V _R = 0	t = 10 ms (50 Hz) t = 8.3 ms (60 Hz)	423 000 403 000	A ² s
T _{VJ}			-40...+150	°C
T _{VJM}			150	°C
T _{stg}			-40...+125	°C
V _{ISOL}	50/60 Hz, RMS I _{ISOL} ≤ 1 mA	t = 1 min t = 1 s	3000 3600	V~
M _d	Mounting torque (M6) Terminal connection torque (M8)		4.5-7/40-62 Nm/lb.in. 11-13/97-115 Nm/lb.in.	
Weight	Typical including screws		750	g

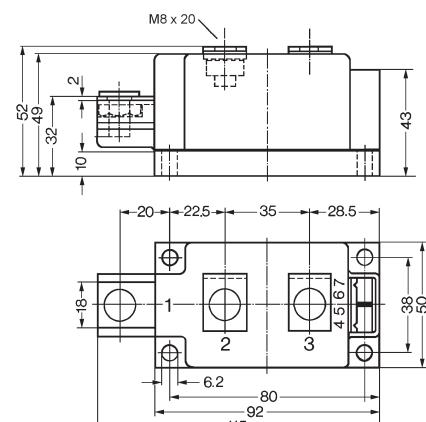
Symbol	Conditions	Characteristic Values		
I _{RRM}	T _{VJ} = T _{VJM} ; V _R = V _{RRM}	30	mA	
V _F	I _F = 600 A; T _{VJ} = 25°C	1.32	V	
V _{TO}	For power-loss calculations only	0.8	V	
r _T	T _{VJ} = T _{VJM}	0.6	mΩ	
R _{thJC}	per diode; DC current	0.12	K/W	
	per module	0.06	K/W	
R _{thJK}	per diode; DC current	0.16	K/W	
	per module	0.08	K/W	
Q _S	T _{VJ} = 125°C; I _F = 400 A; -di/dt = 50 A/μs	700	μC	
	I _{RM}	260	A	
d _S	Creeping distance on surface	12.7	mm	
d _A	Creepage distance in air	9.6	mm	
a	Maximum allowable acceleration	50	m/s ²	

Data according to IEC 60747 and refer to a single diode unless otherwise stated.

IXYS reserves the right to change limits, test conditions and dimensions.

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Dimensions in mm (1 mm = 0.0394")



Optional accessories for modules:
Keyed Gate/Cathode twin plugs with wire length = 350 mm, gate = yellow, cathode = red
Type ZY 180 L (L = Left for pin pair 4/5) UL 758, style 1385
Type ZY 180 R (R = Right for pin pair 6/7) CSA class 5851, guide 460-1-1

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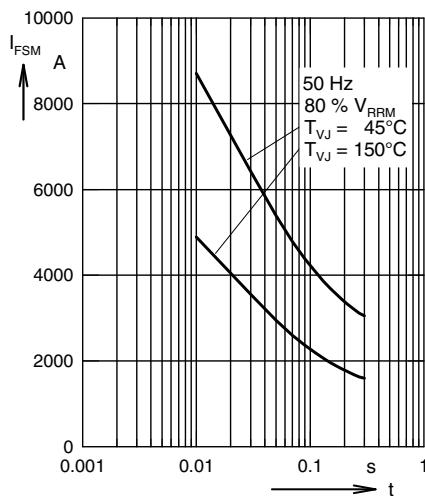


Fig. 1 Surge overload current
 I_{FSM} : Crest value, t: duration

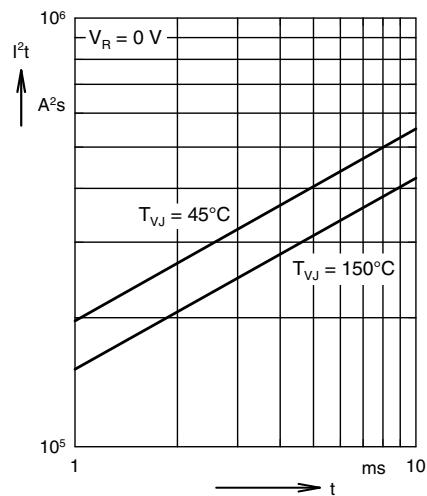


Fig. 2 I^2t versus time (1-10 ms)

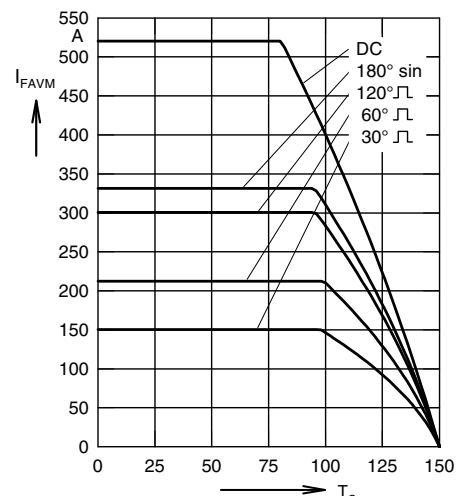


Fig. 3 Maximum forward current at case temperature

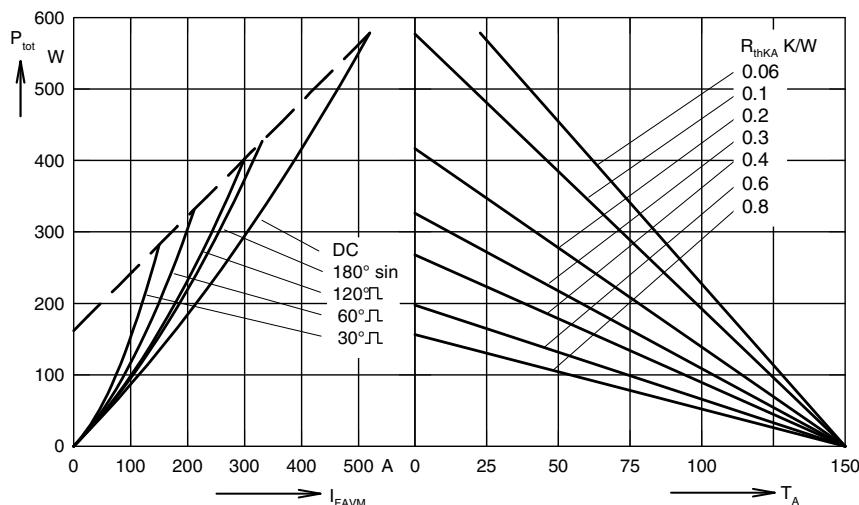


Fig. 4 Power dissipation vs. forward current and ambient temperature (per diode)

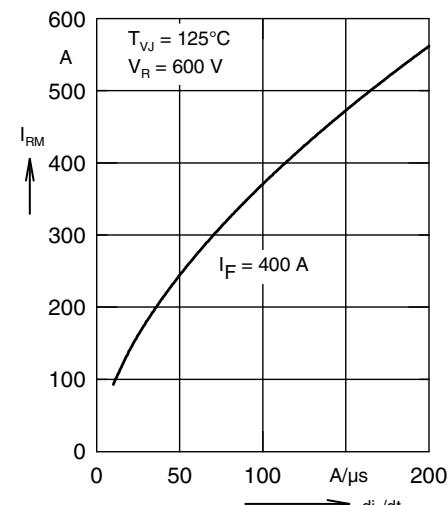


Fig. 5 Typ. peak reverse current
 I_{RM} versus $-di_F/dt$

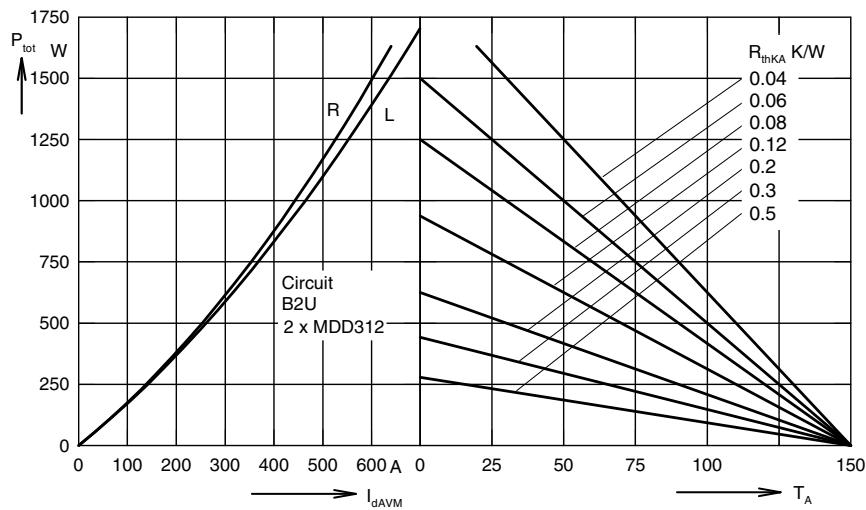


Fig. 6 Single phase rectifier bridge: Power dissipation vs. direct output current and ambient temperature R = resistive load, L = inductive load

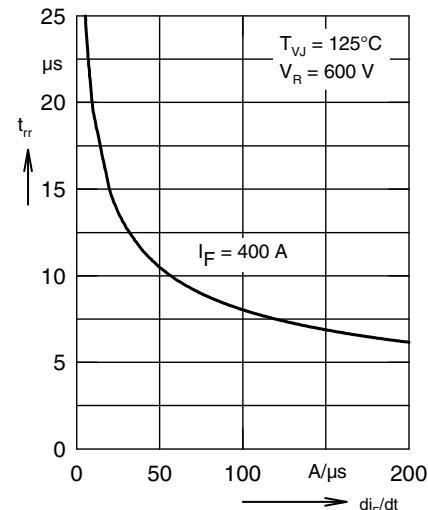


Fig. 7 Typ. recovery time t_{rr}
versus $-di_F/dt$

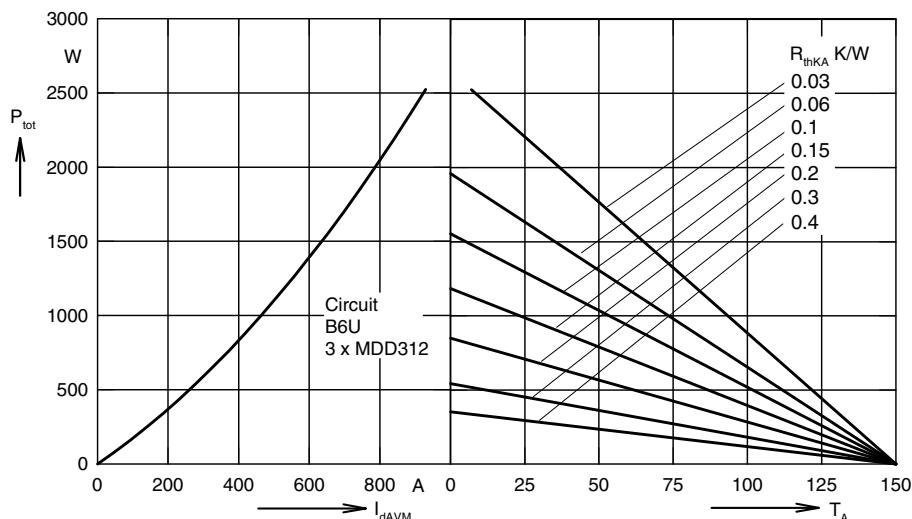


Fig. 8 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

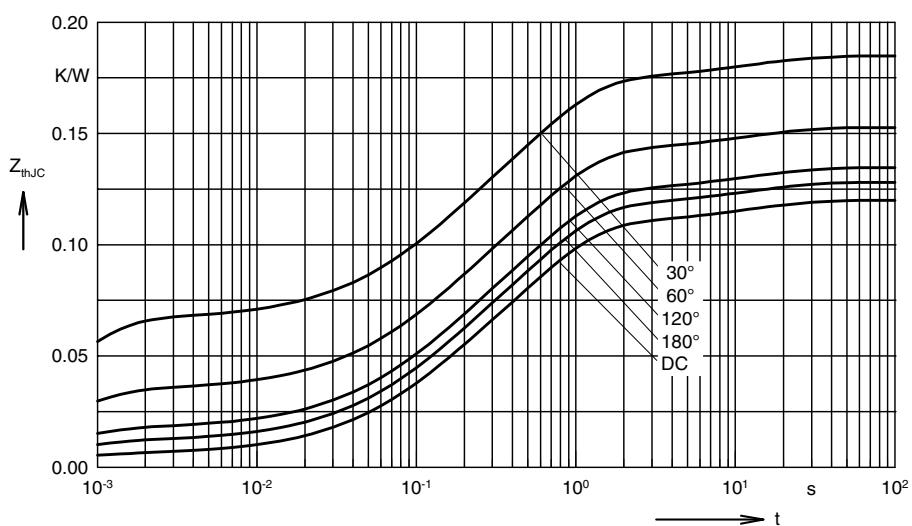


Fig. 9 Transient thermal impedance junction to case (per diode)

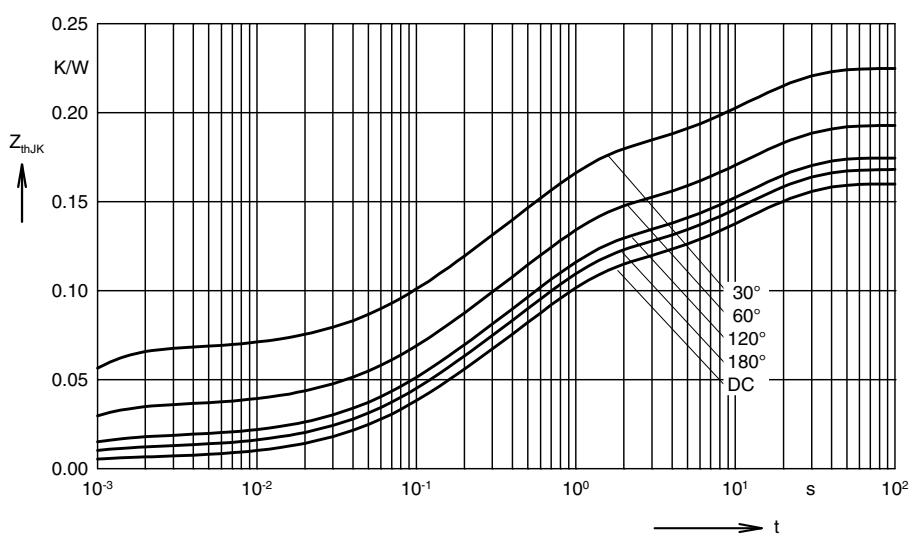


Fig. 10 Transient thermal impedance junction to heatsink (per diode)